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March 2009

FDS6673BZ

P-Channel PowerTrench® MOSFET

-30V, -14.5A, 7.8mΩ

General Description

This P-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench process that has been especially tailored to minimize the on-state resistance.

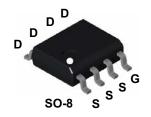
This device is well suited for Power Management and load switching applications common in Notebook Computers and Portable Battery Packs.

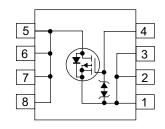
Features

- $Max r_{DS(on)} = 7.8 m\Omega$, $V_{GS} = -10 V$, $I_D = -14.5 A$
- Max $r_{DS(on)} = 12m\Omega$, $V_{GS} = -4.5V$, $I_D = -12A$
- Extended V_{GS} range (-25V) for battery applications
- HBM ESD protection level of 6.5kV typical (note 3)
- High performance trench technology for extremely low r_{DS(on)}
- High power and current handling capability



■ RoHS compliant





MOSFET Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{DS}	Drain to Source Voltage	-30	V
V_{GS}	Gate to Source Voltage	±25	V
	Drain Current -Continuous (Note1a)	-14.5	Α
ID	-Pulsed	-75	Α
	Power Dissipation for Single Operation (Note1a)	2.5	
P_{D}	(Note1b)	1.2	W
	(Note1c)	1.0	
T _J , T _{STG}	Operating and Storage Temperature	-55 to 150	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance , Junction to Ambient (Note 1a)	50	°C/W
$R_{\theta JC}$	Thermal Resistance , Junction to Case (Note 1)	25	°C/W

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape Width	Quantity
FDS6673BZ	FDS6673BZ	13"	12mm	2500 units

Electrical Characteristics T_J = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	Off Characteristics						
B _{VDSS}	Drain to Source Breakdown Voltage	$I_D = -250 \mu A, V_{GS} = 0V$	-30			V	
$\frac{\Delta B_{VDSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	I_D = -250 μ A, referenced to 25°C		-20		mV/°C	
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -24V, V_{GS} = 0V$			-1	μΑ	
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 25V, V_{DS} = 0V$			±10	μΑ	

On Characteristics (Note 2)

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = -250 \mu A$	-1	-1.9	-3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I_D = -250 μ A, referenced to 25°C		8.1		mV/°C
r _{DS(on)} Drain to Source On Resistance	$V_{GS} = -10V$, $I_D = -14.5A$		6.5	7.8		
	Drain to Source On Resistance	$V_{GS} = -4.5V, I_D = -12A$		9.6	12	$_{m\Omega}$
		$V_{GS} = -10V, I_D = -14.5A$ $T_J = 125^{\circ}C$		9.7	12	11132
9 _{FS}	Forward Transconductance	$V_{DS} = -5V, I_{D} = -14.5A$		60		S

Dynamic Characteristics

C _{iss}	Input Capacitance	\\\\ 45\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	3500	4700	pF
C _{oss}	Output Capacitance	$V_{DS} = -15V, V_{GS} = 0V,$ f = 1.0MHz	600	800	pF
C _{rss}	Reverse Transfer Capacitance	1 = 1.000112	600	900	pF

Switching Characteristics (Note 2)

t _{d(on)}	Turn-On Delay Time			14	26	ns
t _r	Rise Time	$V_{DD} = -15V, I_{D} = -1A$ $V_{GS} = -10V, R_{GS} = 6\Omega$		16	29	ns
t _{d(off)}	Turn-Off Delay Time			225	36	ns
t _f	Fall Time			105	167	ns
Qg	Total Gate Charge	$V_{DS} = -15V, V_{GS} = -10V,$ $I_{D} = -14.5A$		88	124	nC
Q_g	Total Gate Charge	V 45V V 5V		46	65	nC
Q_{gs}	Gate to Source Gate Charge	$V_{DS} = -15V, V_{GS} = -5V,$ $I_{D} = -14.5A$		8		nC
Q_{gd}	Gate to Drain Charge	ID = -14.5A		23.5		nC

Drain-Source Diode Characteristics

V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0V, I_S = -2.1A$	-0.7	-1.2	V
t _{rr}	Reverse Recovery Time	$I_F = 14.5A$, $di/dt = 100A/\mu s$		45	ns
Q _{rr}	Reverse Recovery Charge	$I_F = 14.5A$, $di/dt = 100A/\mu s$		34	nC

1: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design while R_{0CA} is determined by the user's board design.



a) 50 °C/W (10 sec) when mounted on a 1 in² pad of 2 oz copper



QQQ b) 105 °C/W when mounted on a .04 in² pad of 2 oz



 $\begin{picture}(20,0) \put(0,0){\line(0,0){125}} \put(0,0){\line(0,0){125$

Scale 1:1 on letter size paper

- 2: Pulse Test: Pulse Width < 300 µs, Duty Cycle < 2.0%.
- 3: The diode connected between the gate and source serves only as protection against ESD. No gate overvoltage rating is implied.

Typical Characteristics T_J = 25°C unless otherwise noted

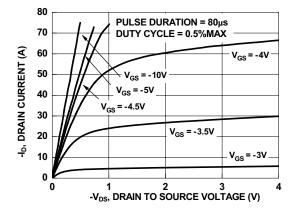


Figure 1. On Region Characteristics

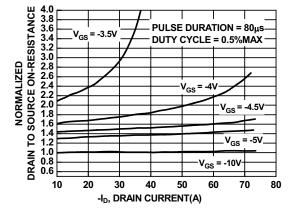


Figure 2. Normalized On-Resistance vs Drain **Current and Gate Voltage**

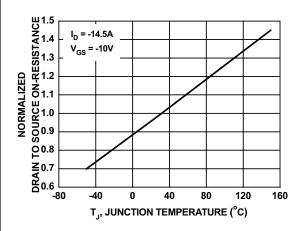


Figure 3. Normalized On Resistance vs Junction Temperature

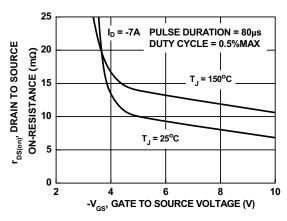


Figure 4. On-Resistance vs Gate to Source Voltage

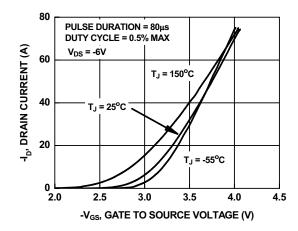


Figure 5. Transfer Characteristics

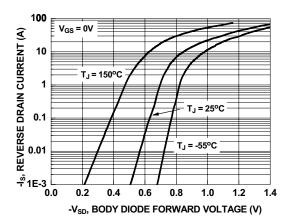
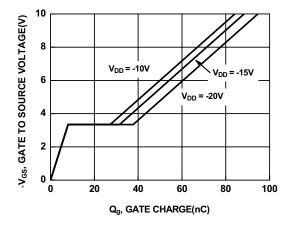


Figure 6. Source to Drain Diode Forward **Voltage vs Source Current**

3 FDS6673BZ Rev. B2





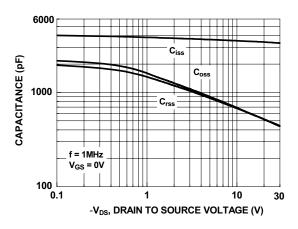
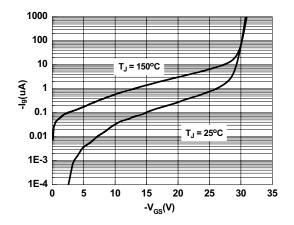


Figure 7. Gate Charge Characteristics

Figure 8. Capacitance vs Drain to Source Voltage



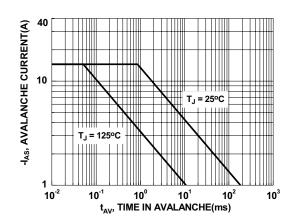
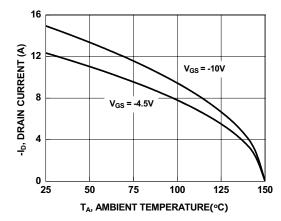


Figure 9. $I_g vs V_{GS}$

Figure 10. Unclamped Inductive Switching Capability



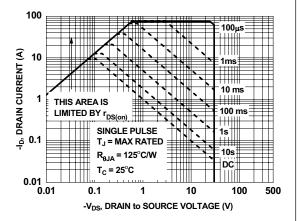


Figure 11. Maximum Continuous Drain Current vs
Ambient Temperature

Figure 12. Forward Bias Safe Operating Area

Typical Characteristics $T_J = 25$ °C unless otherwise noted

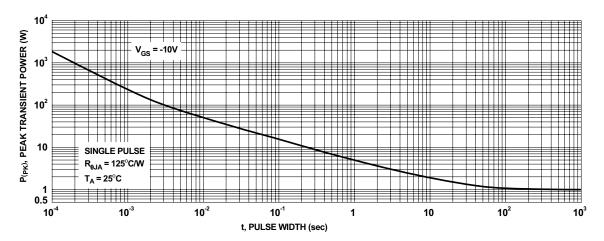


Figure 13. Single Pulse Maximum Power Dissipation

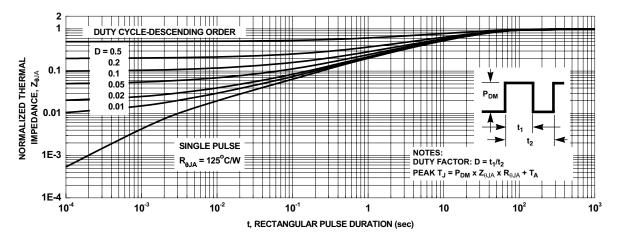


Figure 14. Junction-to-Ambient Transient Thermal Response Curve





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